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## **RFMD(R) Expands Foundry Services Offerings to Include Gallium Arsenide (GaAs) Technologies Manufactured in Europe**

GREENSBORO, N.C., Sep 29, 2010 (GlobeNewswire via COMTEX News Network) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced the Company has added its world-class Gallium Arsenide (GaAs) technology to RFMD's foundry services portfolio and will begin providing a full suite of GaAs Pseudomorphic High Electron Mobility Transistor (pHEMT) technologies to customers of its Foundry Services business unit.

Specifically, RFMD will make available three distinct GaAs pHEMT technologies optimized for high power, low noise and RF switching products. RFMD's 0.3-micron pHEMT technology delivers high power and is optimized for X-band phased array power amplifiers (PAs) and 8-16 GHz wideband military electronic warfare jammers. RFMD's 0.25-micron pHEMT technology delivers low noise, medium power and high linearity and is targeted at applications including low noise front ends and transmitter MMICs. RFMD's 0.6-micron pHEMT technology provides low noise and high linearity switching of RF signals and is designed for applications including wireless front ends and transmit/receive modules.

All of the process technologies are manufactured in RFMD's Newton Aycliffe, United Kingdom fab, providing RFMD's Foundry Services customers access to European technology with ease of European import/export controls.

RFMD currently provides Foundry Services customers access to two of RFMD's gallium nitride (GaN) process technologies from its Greensboro, NC wafer fab : GaN1, targeted at high power applications, and GaN2, targeted at high linearity applications. RFMD also offers an Integrated Passive Component (IPC) technology optimized to complement high power applications. RFMD's advanced GaAs pHEMT technologies are complementary to the Company's GaN technologies and other power semiconductor technologies for the design of multi-chip modules (MCMs).

Bob Van Buskirk, president of RFMD's Multi-Market Products Group (MPG), said, "RFMD is the world's largest manufacturer of III-V circuits for electronics, including both GaAs and GaN. For the last 15 years RFMD has been supplying our customers world-class products manufactured in our wafer fabrication facilities. Now we are presenting this same opportunity to others. With our world class GaAs technology, technology expertise, high volume manufacturing, industry-leading cycle times and unprecedented levels of support, our foundry service enables a wide range of foundry customers to utilize advanced compound semiconductor technologies in an efficient and cost effective business model."

RFMD's Foundry Services business unit was formed to deliver RFMD's high-reliability, high-performance and price-competitive process technologies to external foundry customers immediately upon process qualification and production release.

To arrange a meeting with RFMD Foundry Services staff during European Microwave, in Paris, France, September 28-30, 2010, or during Compound Semiconductor Integrated Circuits Symposium, in Monterey, California, the week of October 4th, 2010, please contact [RFMDFoundryServices@rfmd.com](mailto:RFMDFoundryServices@rfmd.com). Additional information can be obtained by visiting RFMD's website at <http://www.rfmd.com> and clicking on "Foundry."

### About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance semiconductor components. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at [www.rfmd.com](http://www.rfmd.com).

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

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